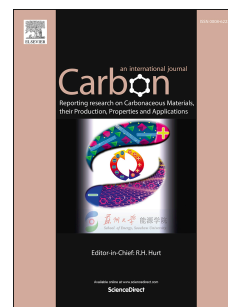


Accepted Manuscript

Low temperature diamond growth arising from ultrafast pulsed-laser pretreatment

Halina Krzyżanowska, William F. Paxton, Mesut Yilmaz, Anthony Mayo, John Kozub, Mick Howell, Justin Gregory, James E. Butler, Weng Poo Kang, Richard Mu, Jimmy L. Davidson, Norman H. Tolk



PII: S0008-6223(18)30092-7

DOI: [10.1016/j.carbon.2018.01.083](https://doi.org/10.1016/j.carbon.2018.01.083)

Reference: CARBON 12824

To appear in: *Carbon*

Received Date: 24 August 2017

Revised Date: 20 January 2018

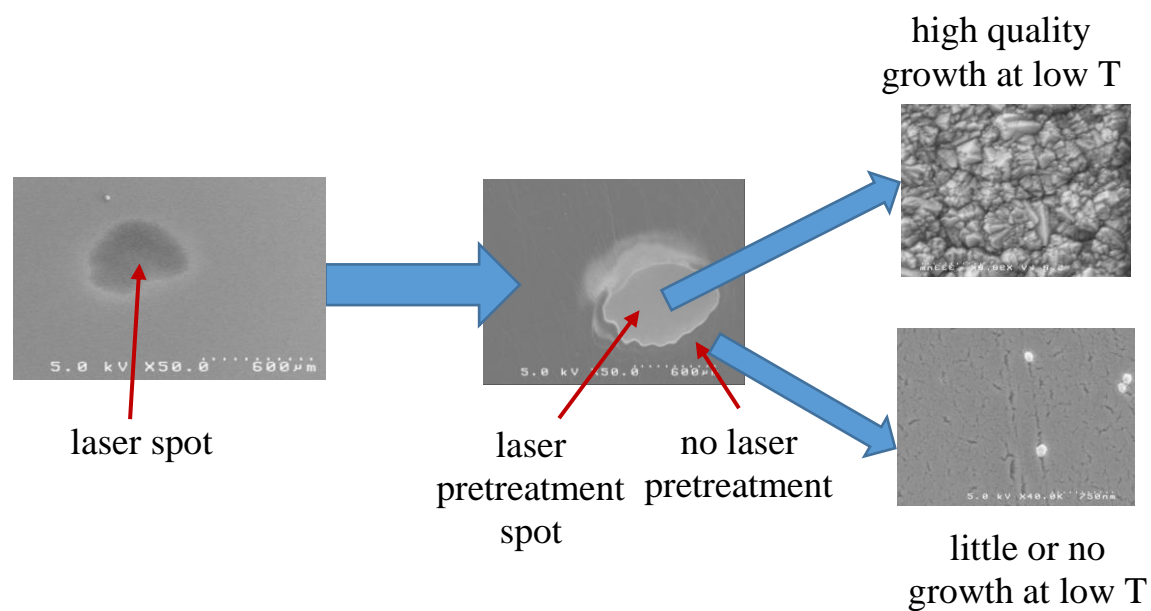
Accepted Date: 22 January 2018

Please cite this article as: H. Krzyżanowska, W.F. Paxton, M. Yilmaz, A. Mayo, J. Kozub, M. Howell, J. Gregory, J.E. Butler, W.P. Kang, R. Mu, J.L. Davidson, N.H. Tolk, Low temperature diamond growth arising from ultrafast pulsed-laser pretreatment, *Carbon* (2018), doi: 10.1016/j.carbon.2018.01.083.

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localized ultrafast laser
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CVD growth at low temperature



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